

# Complementary Silicon High-Power Transistors

... for general-purpose power amplifier and switching applications.

- 10 A Collector Current
- Low Leakage Current —  $I_{CEO} = 0.7 \text{ mA @ } 60 \text{ V}$
- Excellent dc Gain —  $h_{FE} = 40 \text{ Typ @ } 3.0 \text{ A}$
- High Current Gain Bandwidth Product —  $h_{fe} = 3.0 \text{ min @ } I_C = 0.5 \text{ A, } f = 1.0 \text{ MHz}$

## MAXIMUM RATINGS

Rating	Symbol	TIP33B TIP34B	TIP33C TIP34C	Unit
Collector-Emitter Voltage	$V_{CEO}$	80 V	100 V	Vdc
Collector-Base Voltage	$V_{CB}$	80 V	100 V	Vdc
Emitter-Base Voltage	$V_{EB}$	5.0		Vdc
Collector Current — Continuous Peak (1)	$I_C$	10 15		Adc
Base Current — Continuous	$I_B$	3.0		Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	80 0.64		Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +150		$^\circ\text{C}$

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.56	$^\circ\text{C/W}$
Junction-To-Free-Air Thermal Resistance	$R_{\theta JA}$	35.7	$^\circ\text{C/W}$

(1) Pulse Test: Pulse Width = 10 ms, Duty Cycle  $\leq 10\%$ .

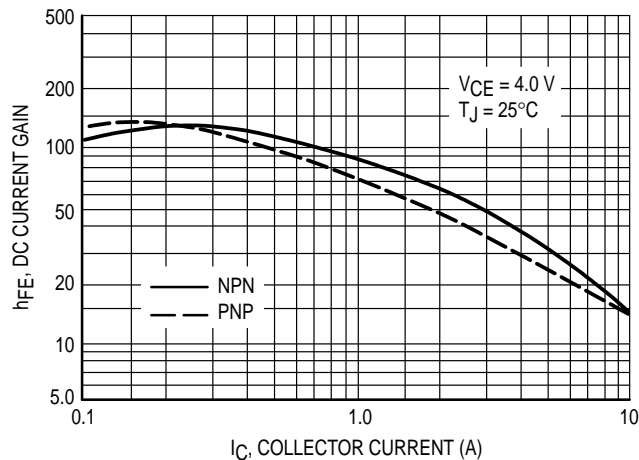


Figure 1. DC Current Gain

Preferred devices are Motorola recommended choices for future use and best overall value.

**NPN**  
**TIP33B\***  
  
**TIP33C**  
**PNP**  
**TIP34B\***  
  
**TIP34C**

\*Motorola Preferred Device

**10 AMPERE**  
**COMPLEMENTARY**  
**SILICON**  
**POWER TRANSISTORS**  
**100 VOLTS**  
**80 WATTS**

**CASE 340D-01**  
**TO-218AC**

# TIP33B TIP33C TIP34B TIP34C

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector–Emitter Sustaining Voltage (1) ( $I_C = 30\text{ mA}$ , $I_B = 0$ )	$V_{CEO(sus)}$	80 100	— —	Vdc
Collector–Emitter Cutoff Current ( $V_{CE} = 60\text{ V}$ , $I_B = 0$ )	$I_{CEO}$	—	0.7	mA
Collector–Emitter Cutoff Current ( $V_{CE} = \text{Rated } V_{CEO}$ , $V_{EB} = 0$ )	$I_{CES}$	—	0.4	mA
Emitter–Base Cutoff Current ( $V_{EB} = 5.0\text{ V}$ , $I_C = 0$ )	$I_{EBO}$	—	1.0	mA

## ON CHARACTERISTICS (1)

DC Current Gain ( $I_C = 1.0\text{ A}$ , $V_{CE} = 4.0\text{ V}$ ) ( $I_C = 3.0\text{ A}$ , $V_{CE} = 4.0\text{ V}$ )	$h_{FE}$	40 20	— 100	—
Collector–Emitter Saturation Voltage ( $I_C = 3.0\text{ A}$ , $I_B = 0.3\text{ A}$ ) ( $I_C = 10\text{ A}$ , $I_B = 2.5\text{ A}$ )	$V_{CE(sat)}$	— —	1.0 4.0	Vdc
Base–Emitter On Voltage ( $I_C = 3.0\text{ A}$ , $V_{CE} = 4.0\text{ V}$ ) ( $I_C = 10\text{ A}$ , $V_{CE} = 4.0\text{ V}$ )	$V_{BE(on)}$	— —	1.6 3.0	Vdc

## DYNAMIC CHARACTERISTICS

Small–Signal Current Gain ( $I_C = 0.5\text{ A}$ , $V_{CE} = 10\text{ V}$ , $f = 1.0\text{ kHz}$ )	$h_{fe}$	20	—	—
Current–Gain — Bandwidth Product ( $I_C = 0.5\text{ A}$ , $V_{CE} = 10\text{ V}$ , $f = 1.0\text{ MHz}$ )	$f_T$	3.0	—	MHz

(1) Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

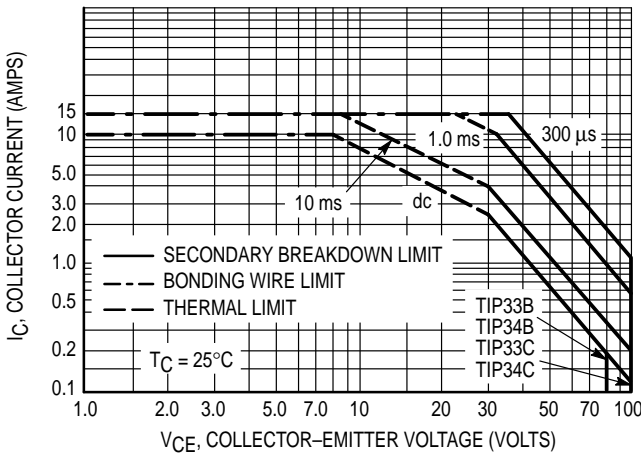


Figure 2. Maximum Rated Forward Bias Safe Operating Area

## FORWARD BIAS

The Forward Bias Safe Operating Area represents the voltage and current conditions these devices can withstand during forward bias. The data is based on  $T_C = 25^\circ\text{C}$ ;  $T_J(\rho k)$  is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10%, and must be derated thermally for  $T_C > 25^\circ\text{C}$ .

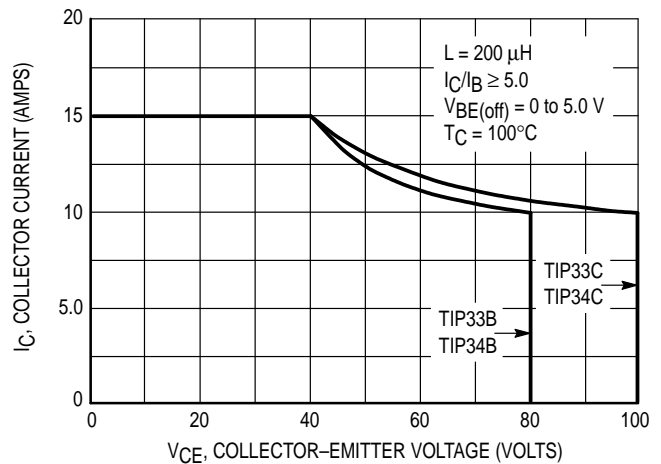
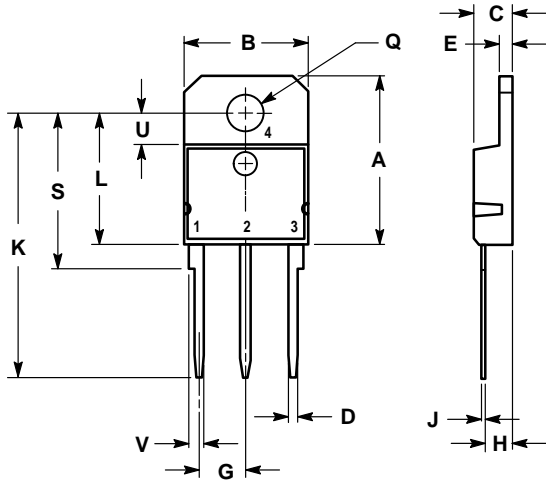


Figure 3. Maximum Rated Forward Bias Safe Operating Area

## REVERSE BIAS

The Reverse Bias Safe Operating Area represents the voltage and current conditions these devices can withstand during reverse biased turn-off. This rating is verified under clamped conditions so the device is never subjected to an avalanche mode.

PACKAGE DIMENSIONS




NOTES:  
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	19.00	19.60	0.749	0.771
B	14.00	14.50	0.551	0.570
C	4.20	4.70	0.165	0.185
D	1.00	1.30	0.040	0.051
E	1.45	1.65	0.058	0.064
G	5.21	5.72	0.206	0.225
H	2.60	3.00	0.103	0.118
J	0.40	0.60	0.016	0.023
K	28.50	32.00	1.123	1.259
L	14.70	15.30	0.579	0.602
Q	4.00	4.25	0.158	0.167
S	17.50	18.10	0.689	0.712
U	3.40	3.80	0.134	0.149
V	1.50	2.00	0.060	0.078

STYLE 1:  
 PIN 1. BASE  
 2. COLLECTOR  
 3. EMITTER  
 4. COLLECTOR

CASE 340D-01  
 TO-218AC  
 ISSUE A

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